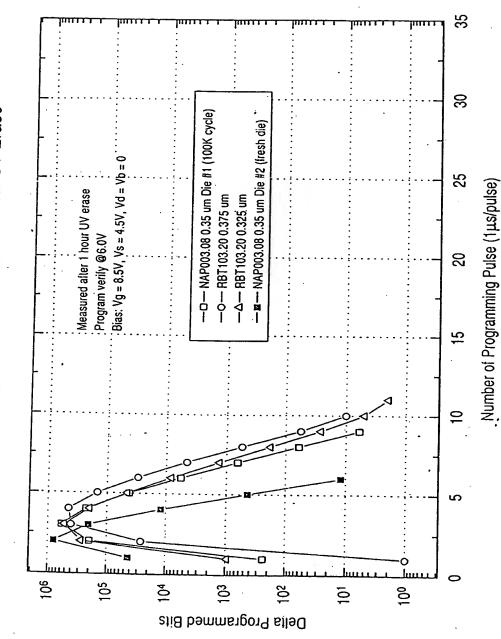


—ם— NAP003.08 0.35 µm Die #1 (100k cycle) 8 Bias: Vg = 8.5V, Vd = 4.5V, Vs = Vb = 0 Drain Side Program Rate Distribution After UV Erase Measured after 1 hour UV erase —O— RBT103.20 0.375 µm —А— RBT103.20 0.325 µm 25 Number of Programming Pulse (1μs/pulse) Program verify @6.0V 23 . 9 106 9 9 Delta Programmed Bits

Source Side Program Rate Distribution After UV Erase



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